

Figure 1. Process flow of recycling the Pb source from spent lead-acid batteries.

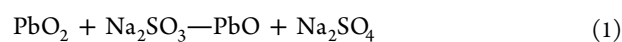
always been a cause of concern for the perovskite commercial applications. Reducing leakage and improving recycle efficiency of Pb are the two main solutions for addressing the lead toxicity concern and the environmental pollution.³⁷ Currently, it is a common process to prepare lead ingots in lead regeneration through the fire smelting process.³⁸ However, lead composites such as lead sulfate require a high temperature of more than 1000 °C to be decomposed, which results in environmental pollution due to the emission of lead particles and sulfur dioxide into the atmosphere. Another effective and straightforward strategy for reducing environmental pollution is to find alternative lead sources that are abundant, inexpensive, and allow safe extraction and processing procedures.³⁹ Lead-acid batteries are widely used in automotive vehicles, which produce massive environmentally hazardous wastes including Pb anodes and cathodes after retirement. These hazardous Pb electrodes are required to be disposed or reprocessed appropriately.³⁷ Therefore, the recovery of lead-acid batteries provides an alternative and readily available lead source for fabricating Pb-based solar cells.

In a pioneering work, Chen et al. utilized PbI_2 extracted from lead-acid batteries to fabricate MAPbI_3 halide perovskite solar cells and achieved a PCE of 9.37%.³⁸ Very recently, Li et al. further improved the efficiency of MAPbI_3 halide perovskite solar cells to over 17% using recycled $\text{Pb}(\text{Ac})_2$ from lead-acid batteries. These achievements prove that the lead source from lead-acid batteries could be used in halide perovskite thin-film photovoltaics.⁴⁰ However, the device performance in these works is far inferior to those fabricated from commercial PbI_2 due to the presence of impurity elements in the recycled lead source. In addition, the above-reported methods still require high-temperature sintering processes (>500 °C) to extract Pb from the spent lead acid batteries. Therefore, there is an urgent need to develop a safe approach of low-temperature recycling of Pb and to fill the efficiency gap between conventional and recycled perovskite photovoltaics.

In contrast to the bulk film counterpart, perovskite QDs in principle feature a high tolerance of impurities in the precursor since the impurities tend to be expelled from the small crystalline cores during colloidal nucleation, thus reducing the possibility of defect formation.⁴¹ Therefore, the recycled Pb source with low purity and cost is more favorable to synthesize

perovskite QDs for optoelectronic device fabrication. In this work, we conceived a facile low-temperature solution process and successfully extracted Pb source from spent car lead-acid batteries to synthesize PbI_2 powders. The obtained PbI_2 was further utilized to synthesize CsPbI_3 QDs, which demonstrated similar photophysical performance including PLQY and carrier lifetime compared to those synthesized from commercial PbI_2 . The champion solar cell fabricated from the recycled PbI_2 achieved a high PCE of 14.0%, which is comparable to the 14.7% efficiency of the solar cell made from the commercial PbI_2 . These results endorse the effectiveness of the proposed low-temperature solution process for reusing waste Pb and validates the compatibility of recycled Pb source to synthesize high-quality perovskite QDs for efficient optoelectronics, which not only reduces the lead waste issue but also promotes the added value of spent batteries.

Figure 1 illustrates the low-temperature recycling process using waste anodes and cathodes collected from spent car batteries to produce PbI_2 end-product. First, a spent lead acid battery was dismantled, and then the acid electrolyte that contains concentrated sulfuric acid was diluted with water and poured out. The electrodes were further rinsed with water several times and air-dried. The anode and cathode materials were mixed for preparing lead paste, which contains PbSO_4 , PbO_2 , and PbO components. To understand the composition of lead paste, ethylenediaminetetraacetic acid (EDTA) complexometric titration was employed for analyzing the content of chemical components.⁴² The weight content of lead paste is 16.6% for PbO , 32.03% for PbO_2 , and 17.71% for PbSO_4 . Afterward, we introduced a facile one-pot solution process to extract the Pb source by mixing lead paste (5 g) with excess Na_2SO_3 (1 g), dilute acetic acid (Ac, 80 mL, 0.4 mmol/mL), and ammonium acetate (NH_4Ac , 0.5 g). Subsequently, the mixture was stirred at 35 °C for 24 h to form lead acetate. After sufficient reaction, the mixture was filtered to obtain a clear lead acetate solution. Then excess hydroiodic acid (HI) was added slowly to the lead acetate solution under stirring, and the formation of yellow PbI_2 precipitate was observed. The yellow solid was collected and dried in vacuum at 60 °C overnight. The detailed reactions of proposed low-temperature recycling are as follows (eqs 1–4):



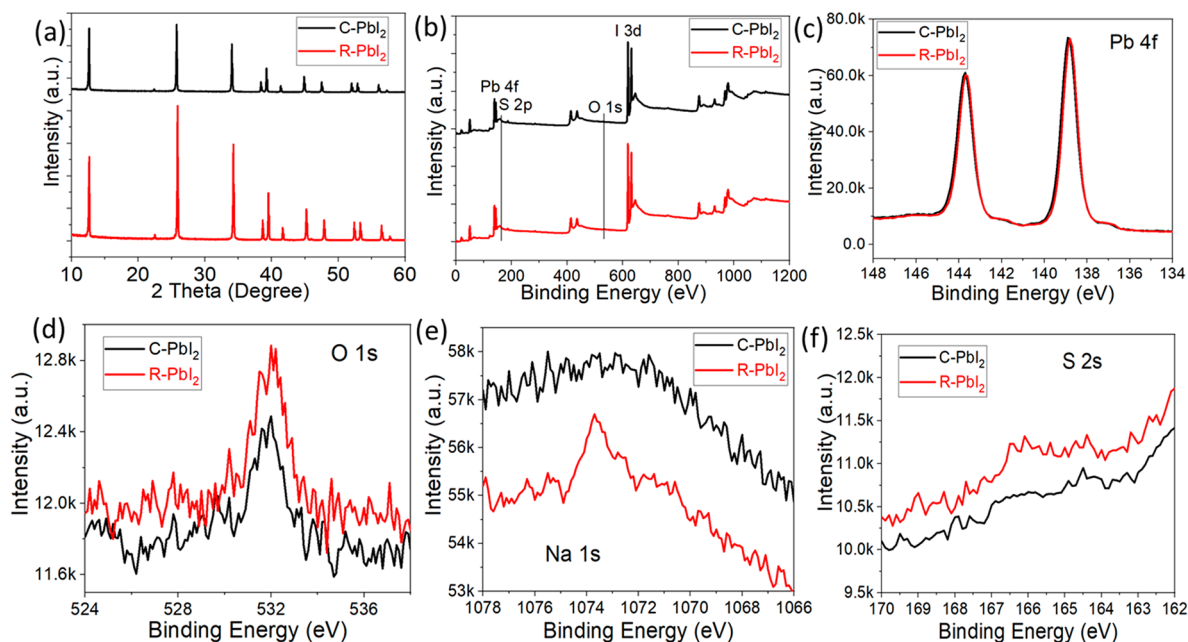
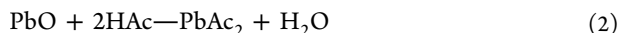


Figure 2. Crystallinity and composition characterizations of C-PbI₂ and R-PbI₂. (a) XRD patterns of C-PbI₂ and R-PbI₂. (b) Full XPS spectra of C-PbI₂ and R-PbI₂. Core XPS spectra of C-PbI₂ and R-PbI₂ in (c) Pb 4f, (d) O 1s, (e) Na 1s, and (f) S 2s binding energy ranges.



The as-obtained PbI₂ powder was characterized to confirm its crystal structure and purity, which is a prerequisite for synthesizing high-quality CsPbI₃ QDs. As a comparison, commercial PbI₂ (Sigma) was also used to fabricate perovskite QD solar cells, and the recycled and commercial PbI₂ were denominated as R-PbI₂ and C-PbI₂, respectively. Figure 2a shows the X-ray powder diffraction (XRD) patterns of both R-PbI₂ and C-PbI₂. Both PbI₂ present identical XRD patterns and no impurity phase is observed, indicating successful synthesis of fine crystalline PbI₂ from the waste lead acid battery.^{43,44} To further verify the purity of PbI₂, X-ray photoelectron spectrum (XPS) measurement was conducted to investigate the elemental composition, valence states, and atomic ratio.⁴⁵ Figure 2b illustrates the full XPS spectra of both kinds of PbI₂, while Figure 2c–f give the core XPS spectra of Pb 4f, O 1s, Na 1s, and S 2s, respectively. For the core XPS spectra of Pb 4f (Figure 2c), two main peaks are observed at 144.2 and 138.9 eV, which are assigned to the Pb 4f 5/2 and Pb 4f 7/2, respectively.⁴⁶ Notably, no peaks were observed at any lower binding energy near the main signals, which suggests the absence of metallic Pb atoms and confirms the purity of PbI₂.⁴⁷ Figure 2d shows that the O 1s peak in the R-PbI₂ is higher than that in the C-PbI₂. Furthermore, Figure 2e,f points out the existence of Na and S elements in the R-PbI₂. Combining the XPS results of O, Na, and S elements, we can conclude that the Na₂SO₃ component was not completely removed from the end-product R-PbI₂. The atomic ratios in both kinds of PbI₂ are summarized in Table 1, in which the high similarity in the elemental composition endorses the application of R-PbI₂ in widespread usages.

Undesirable impurity elements in bulk perovskite thin film usually create defect states and retard their optoelectronic

Table 1. Atomic Ratios of C-PbI₂ and R-PbI₂ Obtained from XPS Results

PbI ₂ type	Pb	S	O	Na	I	C
C-PbI ₂	20.24	2.08	2.69	0.00	58.79	16.20
R-PbI ₂	20.01	2.47	3.01	0.50	57.98	15.96

performance severely due to nonradiative recombination.^{48,49}

On the other hand, colloidal perovskite QDs own a different nucleation mechanism and the famous self-purification effect is regarded as a significant advantage of colloidal synthesis, in which the impurities are easier to be expelled from the nanoscale nucleation cores.^{41,50} Therefore, colloidal perovskite QDs should possess better compatibility with a recycled lead source for high-performance and less polluted optoelectronic applications. As comparison, both C-PbI₂ and R-PbI₂ were employed to synthesize CsPbI₃ QDs using a hot-injection method. Briefly, 0.5 g of PbI₂, 2.5 mL of oleic acid (OA), and 25 mL of octadecene (ODE) were loaded in 100 mL three-neck flask and vacuum pumped under continuous stirring at 100 °C for 1 h. Then, 2.5 mL of oleylamine (OLA) was injected into the flask. After PbI₂ completely dissolved, the temperature was increased to 160 °C under a N₂ flow protection. A volume of 4 mL of Cs-OA precursor solution was injected swiftly into the flask and reacted for 5 s, and the solution was quenched by an ice bath. All synthesis conditions were identical except the PbI₂ source for both batches of CsPbI₃ QDs. The crude CsPbI₃ QDs solution was evenly divided into three centrifugation tubes, and then methyl acetate was added into tubes with a volume ratio of 1:3 (QD solution–methyl acetate). Subsequently, QD precipitate was extracted by centrifugation at the speed of 8000 rpm for 3 min. All of the QD precipitate in three tubes was dispersed with 3 mL of hexane and then precipitated by adding 4.5 mL of methyl acetate and centrifuged again at 8000 rpm for 3 min. Finally, the extracted QDs were dissolved in hexane for characterizations and device fabrication.

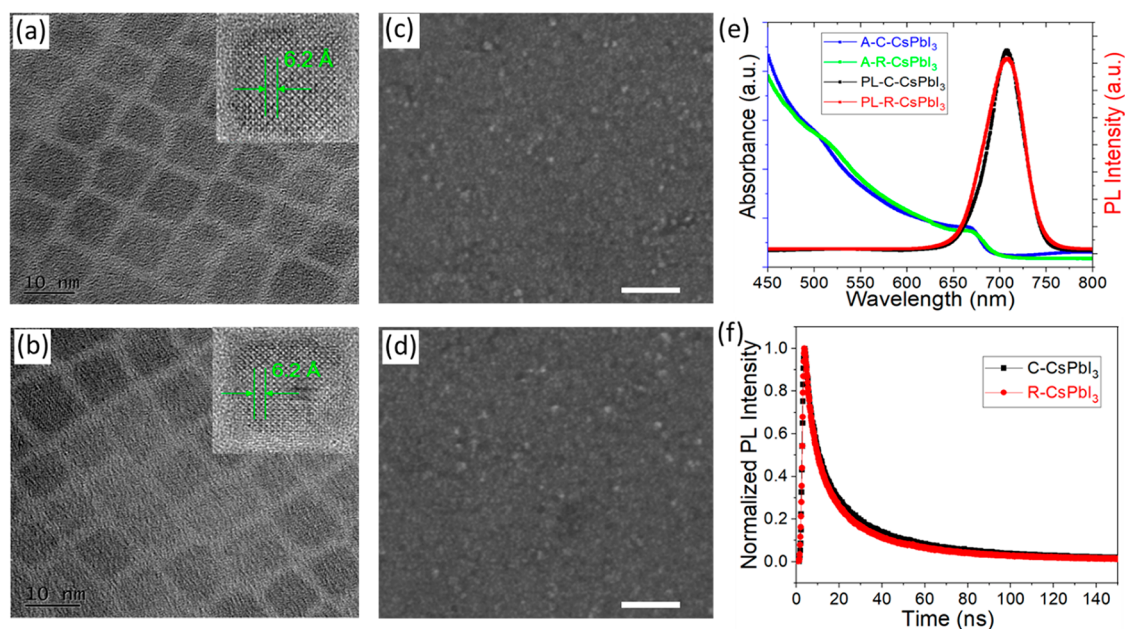


Figure 3. TEM images of (a) C-CsPbI₃ and (b) R-CsPbI₃ QDs. SEM images of (c) C-CsPbI₃ and (d) R-CsPbI₃ QD films; scale bar, 300 nm. (e) Steady-state PL and absorbance spectra of C-CsPbI₃ and R-CsPbI₃ QD films. (f) Time-resolved PL spectra of both QD films.

Both kinds of CsPbI₃ QDs were thoroughly characterized. Transmission electron microscopy (TEM) images of C-CsPbI₃ (synthesized from C-PbI₂) and R-CsPbI₃ QDs (synthesized from the R-PbI₂) in Figure 3a,b, respectively, show that both batches of QDs formed in cubic shape with an average size of 9 nm. High-resolution TEM images of both QDs (see the insets in Figure 3a,b) confirm the formation of the cubic phase of CsPbI₃ with the measured lattice spacings of 6.2 Å corresponding to the $\langle 100 \rangle$ planes. The PLQY measurement provides valuable insight on the defect density, and a higher PLQY often indicates a lower defect density due to suppressed nonradiative recombination. Both batches of CsPbI₃ QDs feature quite comparable PLQY, i.e., 92% for the C-CsPbI₃ and 90% for the R-CsPbI₃ QDs, which are on par with the reported values.^{51–53} Therefore, it can be concluded that both kinds of CsPbI₃ QDs share similar characteristics including size distribution and defect density. In addition, the Na element in R-CsPbI₃ QDs was not detected in XPS results, as shown in Figure S1, implying that Na atoms were expelled out from CsPbI₃ QDs due to the self-purification effect.

Both types of CsPbI₃ QD solution were spin-coated on the SnO₂ nanoparticle (NPs)/ITO substrates and treated with methyl acetate to form dense semiconducting QD films. The scanning electron microscopy (SEM) technique was performed to observe surface morphology. As shown in Figure 3c,d, both films have identical surface morphology, which are densely packed by discrete QDs. Figure 3e shows the absorption and PL characteristics, in which there is no significant difference between C-CsPbI₃ and R-CsPbI₃ QD films. Additionally, carrier lifetime calculated from the time-resolved PL spectra using single-exponent fitting is also very similar, i.e., 4.5 ns for the C-CsPbI₃ and 4.2 ns for the R-CsPbI₃ QD films, which are on a par with reported results.^{31,54} Therefore, both kinds of QD films demonstrate very similar characteristics, confirming the high feasibility of the proposed recycling process for producing reliable alternative lead sources.

First-principles density functional theory (DFT) calculations (Experimental section in the Supporting Information) revealed that the formation energy of Na interstitials, E_f , reaches the minimum when Na⁺ resides on the top of the CsPbI₃ slab surface. Specifically, E_f is 3.11 eV for the Na⁺ residing at the surface (Figure 4a), 3.43 eV for the Na⁺ in the core of CsPbI₃

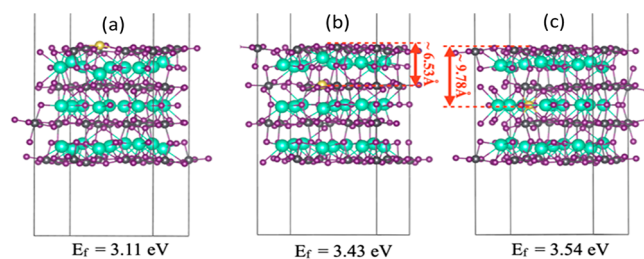


Figure 4. Optimized geometries and formation energies (E_f) of a Na⁺ interstitial defect in a CsPbI₃ slab expressed as a function of distance to the surface. Black lines indicate the boundaries of the simulation cell employed in the first-principles DFT calculations. Cs, Pb, I, and Na atoms are represented with cyan, gray, purple, and yellow spheres, respectively.

QD with a distance of 6.53 Å from the surface (Figure 4b), and 3.54 eV for the Na⁺ with a distance of 9.78 Å from the surface (Figure 4c). The location-dependent trend of E_f indicates that the interstitial Na atoms would migrate from the interior of the slab and prefer to stay at the CsPbI₃ QD surface. It is a general phenomenon that defects can be favorably excluded from the lattice of QDs because they are thermodynamically unstable in the host as a result of their high formation energy.⁵⁵ This calculation result also provides a clue for the energetics involved in doping impurity elements into perovskite nanocrystals. Clearly, the recycled lead source is more suitable for fabricating perovskite QDs than their bulk film counterparts as the self-purification effect can suppress the detrimental effects of impurities.

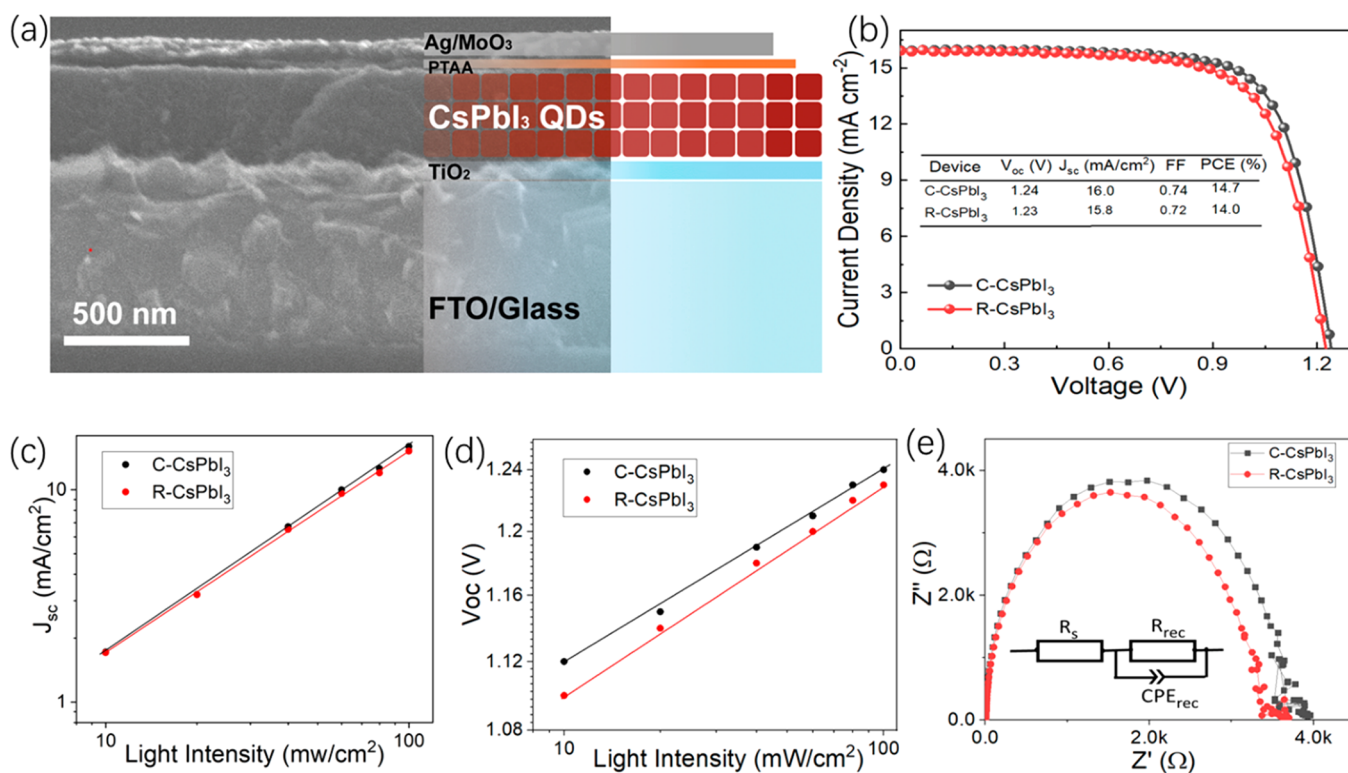


Figure 5. (a) Cross-sectional SEM image of the R-CsPbI₃ QD solar cell. (b) J - V curves. Light intensity dependence of (c) J_{sc} and (d) V_{oc} of both QD solar cells. (e) Corresponding EIS Nyquist plots of the champion devices of C-CsPbI₃ and R-CsPbI₃ QD solar cells.

Table 3. Summary of Performance Statistics for the CsPbI₃ Solar Cells^a

device type	V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF	PCE (%)
C-CsPbI ₃	1.22 ± 0.03 (1.24)	15.7 ± 0.6 (16.0)	0.72 ± 0.02 (0.74)	13.8 ± 0.5 (14.7)
R-CsPbI ₃	1.22 ± 0.03 (1.23)	15.3 ± 0.7 (15.8)	0.71 ± 0.03 (0.72)	13.3 ± 0.5 (14.0)

^aThe champion parameters are in parentheses, and there are 24 devices for each type.

CsPbI₃ QD solar cells were fabricated using the structure of FTO/C-TiO₂/CsPbI₃/PTAA/MoO₃/Ag, where the sprayed TiO₂ compact layer serves as the electron transport layer, CsPbI₃ QDs as the light absorbing layer, and PTAA as the hole transport layer. The experimental details are given in the Supporting Information. Figure 5a shows the cross-sectional SEM image of a complete R-CsPbI₃ QD solar cell, and each layer can be clearly identified. Figure 5b demonstrates the current density–voltage (J - V) curves of the champion solar cells under the reverse scanning direction. The C-CsPbI₃ solar cell achieved a PCE of 14.7% with an open-circuit voltage (V_{oc}) of 1.24 V, a short-circuit current density (J_{sc}) of 16.0 mA/cm², and a fill factor (FF) of 0.74, while the R-CsPbI₃ solar cell delivered a comparable PCE of 14.0% with a V_{oc} of 1.23 V, a J_{sc} of 15.8 mA/cm², and an FF of 0.72. The performance statistics for two batches of solar cells are given in Table 3, and the average efficiency is 13.8% for the C-CsPbI₃ solar cells and 13.3% for the R-CsPbI₃ solar cells, which are comparable with the reported state-of-the-art values,⁵⁴ and a detailed comparison is given in Table S1. Additionally, as shown in Figure S2, the R-CsPbI₃ QD and C-CsPbI₃ cells delivered negligible hysteresis, which is in line with the reported results.⁵⁶

To investigate the charge carrier generation and recombination mechanisms, we probed the recombination processes in both CsPbI₃ QD devices using the light intensity dependence

of J_{sc} and V_{oc} measurements. The power-law dependence of J_{sc} with the light intensity generally obeys the relationship of $J_{sc} \propto I^\alpha$, where I is the light intensity and α is the exponential factor. As shown in Figure 5c, both cells exhibit α values close to unity, i.e., 0.98 for the C-CsPbI₃ device and 0.97 for the R-CsPbI₃ device, indicating that bimolecular recombination does not dominate in both CsPbI₃ QD devices. V_{oc} of the device at different light intensities was also recorded and given in Figure 5d. The slope of V_{oc} versus the light intensity follows nkT/q , where n , k , T , and q are the diode ideality factor, the Boltzmann constant, temperature, and the elementary charge, respectively. The larger diode ideality factor (n) is indicative of more trap-assisted recombination occurring in a cell at open-circuit condition. The slope of the C-CsPbI₃ device ($1.19 kT/q$) is also close to that of the R-CsPbI₃ device ($1.21 kT/q$), suggesting that the trap-assisted recombination in both devices is similar. Additionally, electrochemical impedance spectroscopy (EIS) was applied to study the CsPbI₃ QD devices. The Nyquist plots of C-CsPbI₃ and R-CsPbI₃ QD solar cells measured at 0 V under dark conditions are shown in Figure 5e, and the inset shows the equivalent circuit. The intersection between the spectra and the Z' -axis at high and low frequencies represent the series resistance (R_s) and the recombination resistance (R_{rec}) of the device, respectively. Since the charge transport layers are identical in both devices, the R_s and R_{rec} values are associated with the CsPbI₃ QD films.

The C–CsPbI₃ cell shows a R_s of 23.1 Ω and R_{rec} of 3745.3 Ω , as compared to R_s of 28.6 Ω and R_{rec} of 3635.8 Ω in the R–CsPbI₃ cell. The similar values of R_s and R_{rec} indicate that the quality of both QD films is very close, which is consistent with the similar photovoltaic performance in both cells.

In conclusion, the PbI₂ powder was successfully synthesized from the spent lead acid batteries by using a facile and efficient low-temperature one-pot method, which not only recycles the lead waste of spent batteries but also provides a low-cost and environment-friendly way to synthesize lead precursors. More importantly, we found that the recycled PbI₂ is suitable to synthesize perovskite QDs due to the self-purification effect, which leads to the expulsion of impurity atoms from the lattice of CsPbI₃ QDs. As a result, CsPbI₃ QDs synthesized from both recycled and commercial PbI₂ showed similar physical properties, including size distribution, PLQY, absorbance, and carrier lifetime. The resulting CsPbI₃ QD solar cells achieved PCE of 14.7% and 14.0% for the C–CsPbI₃ and R–CsPbI₃ QD devices, respectively. These results validate that the PbI₂ precursor recycled from spent lead acid batteries with the low-temperature solution process is suitable for QD-based optoelectronic applications.

■ ASSOCIATED CONTENT

SI Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acsmaterialslett.1c00592>.

Experimental section including PbI₂ preparation, CsPbI₃ QD synthesis, and DFT simulations; SEM, XPS, and J – V curves; and table reporting state of the art efficiencies and device structures of CsPbI₃ QD solar cells (PDF)

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Notes

The authors declare no competing financial interest.

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